

PT4800E0000F

Transparent Resin, Medium Directivity
Angle, Thin Package Phototransistor



■ Features

1. Side view detection thin package
2. Plastic mold with opaque resin lens
3. Peak sensitivity wavelength: 800 nm (TYP.)
4. Medium directivity angle ($\Delta\theta \pm 35^\circ$ TYP.)
5. Lead free and RoHS directive compliant

■ Agency Approvals/Compliance

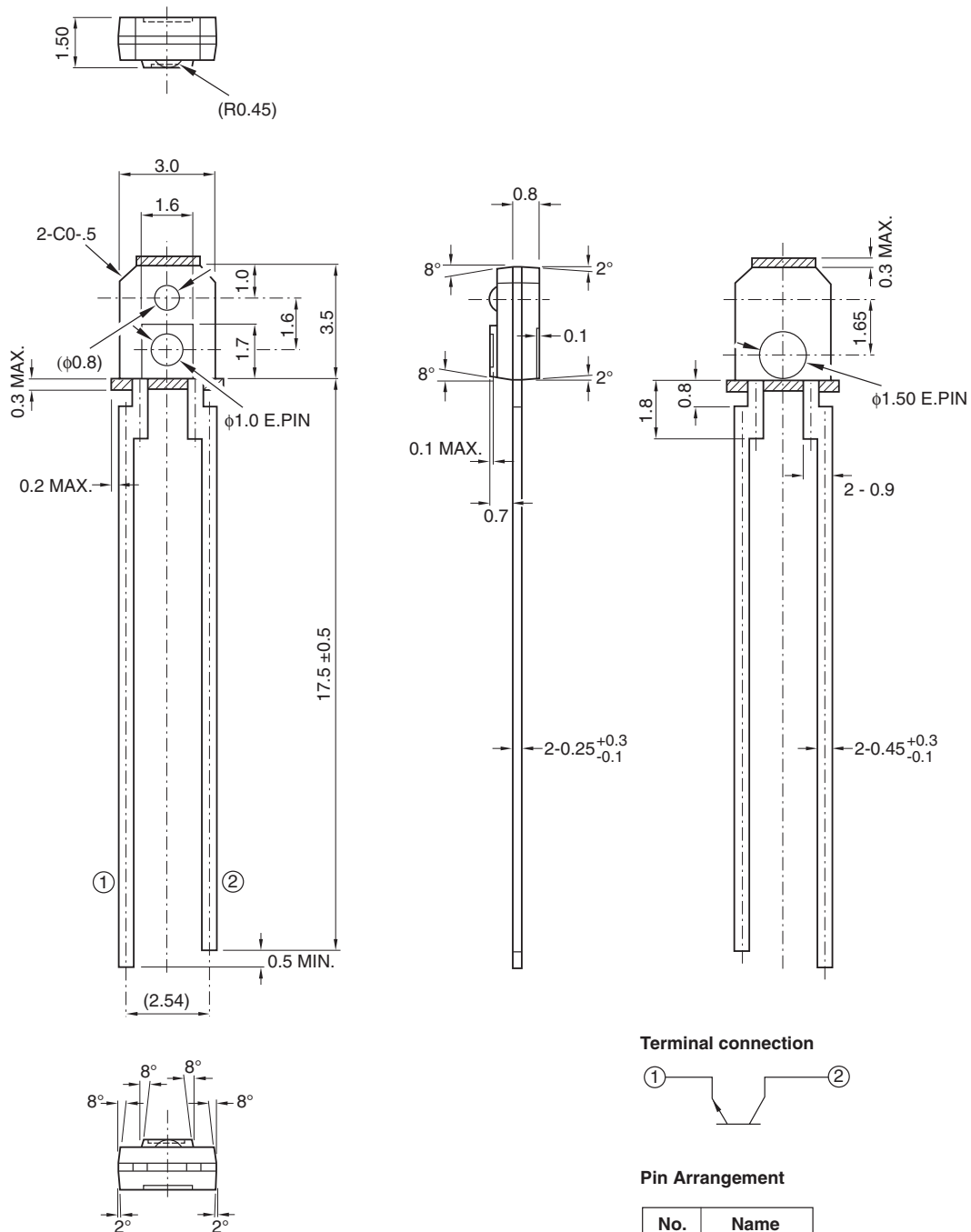
1. Compliant with RoHS directive (2002/95/EC)
2. Content information about the six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (popular name: China RoHS) (Chinese: 电子信息产品污染控制管理办法); refer to page 7.

■ Applications

1. Telecommunications equipment
2. Home Appliances
3. Office automation equipment
4. Audio visual equipment

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In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

External Dimensions



NOTES:

1. Units: mm
2. Unspecified tolerance: ±0.2 mm
3. (): Reference dimensions
4. Package: Transparent epoxy resin
5. The thin burr thickness (0.05 mm MAX.) is not included in outline dimensions
6. Resin protrusion: 0.3 mm MAX.
7. However, the thin burr adhering to the lead is 1.8 mm MAX. from the resin.

Terminal connection



Pin Arrangement

No.	Name
①	Emitter
②	Collector

■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Rating	Unit
Collector-emitter voltage	V_{CEO}	35	V
Emitter-collector voltage	V_{ECO}	6	V
Collector current	I_C	20	mA
Collector power dissipation	P_C	75	mW
Operating temperature	T_{opr}	-25 to +85	°C
Storage temperature	T_{stg}	-40 to +85	°C
Soldering temperature *1	T_{sol}	260	°C

*1 3 s (MAX.) at 1.8 mm from resin edge.

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter	Symbol	Conditions *1	MIN.	TYP.	MAX.	Unit
Collector current	I_C	$E_e = 1 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$	0.12	0.4	1.0	mA
Dark current	I_{CEO}	$E_e = 0$, $V_{CE} = 20 \text{ V}$	—	—	100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$E_e = 10 \text{ mW/cm}^2$, $I_C = 0.5 \text{ mA}$	—	—	0.4	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = 0.1 \text{ mA}$, $E_e = 0$	35	—	—	V
Emitter-collector breakdown voltage	BV_{ECO}	$I_E = 0.01 \text{ mA}$, $E_c = 0$	6	—	—	V
Peak sensitivity wavelength	λ_p	—	—	800	—	nm
Response time (Rise)	t_r	$V_{CE} = 2 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$	—	3.0	—	μs
Response time (Fall)	t_f		—	3.5	—	μs
Half-intensity angle	θ	—	—	± 35	—	degrees

*1 E_e : Irradiance by CIE standard light source A (tungsten lamp)

■ Collector Current Ranking

Rank	Collector Current I_C (mA)
A	0.12 to 0.28
B	0.22 to 0.53
C	0.42 to 1.0

*1 Quantities and ratios of any one ranking in any one shipment are at the discretion of Sharp.

Fig. 1 Collector Power Dissipation vs. Ambient Temperature

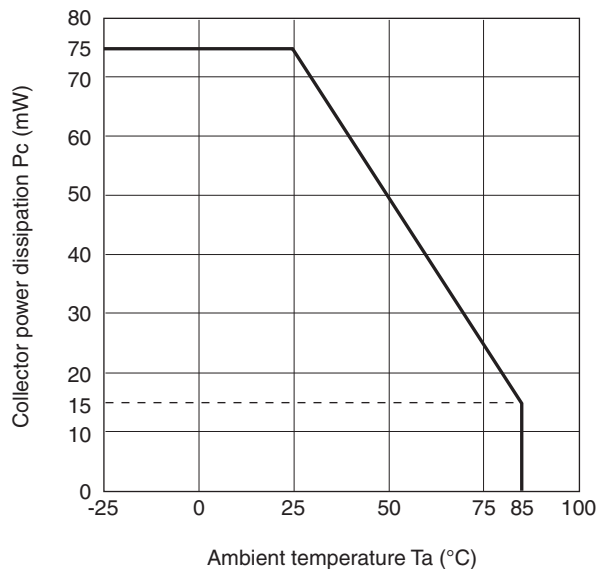


Fig. 3 Collector Dark Current vs. Ambient Temperature

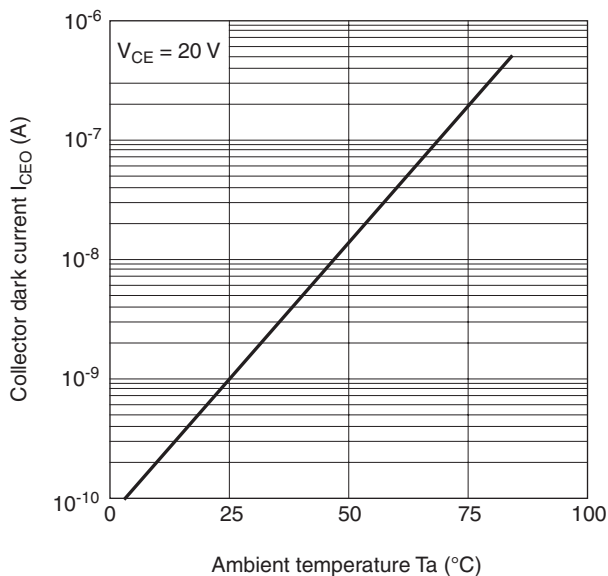


Fig. 2 Spectral Sensitivity (TYP.)

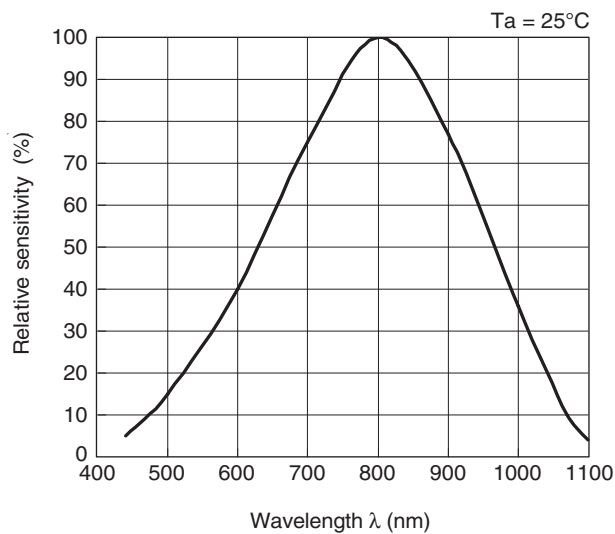


Fig. 4 Relative Collector Current vs. Ambient Temperature

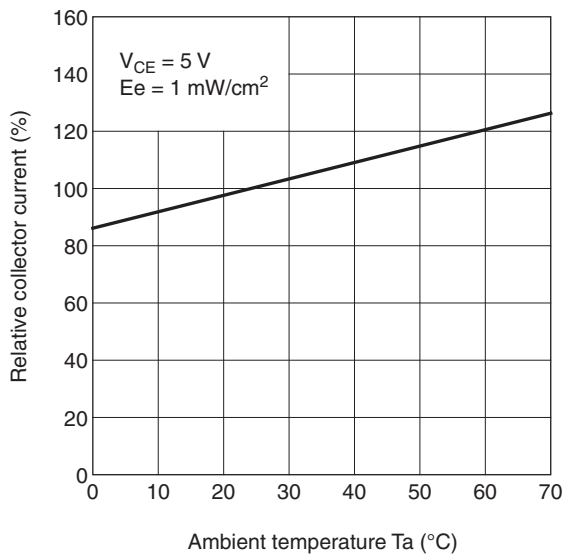


Fig. 5 Collector Current vs. Irradiance

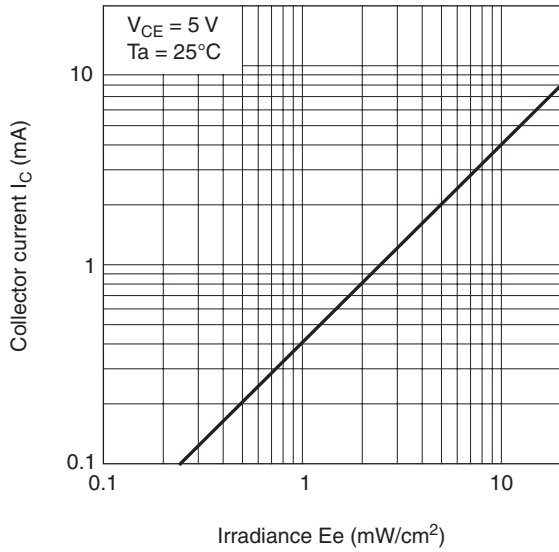


Fig. 7 Response Time vs. Load Resistance

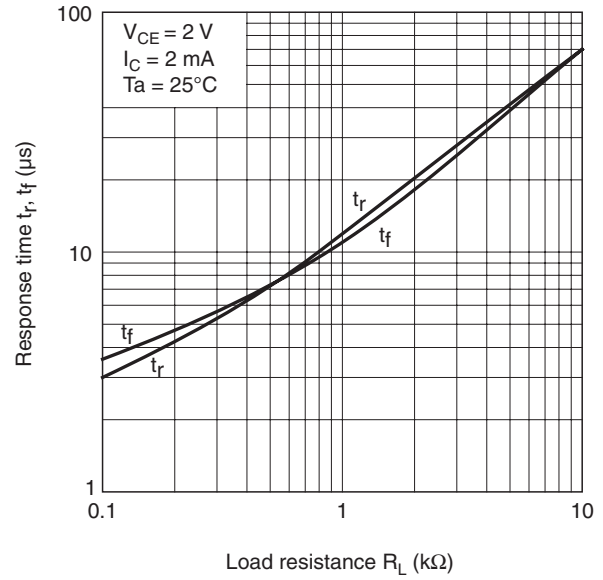


Fig. 6 Collector Current vs. Collector-Emitter Voltage

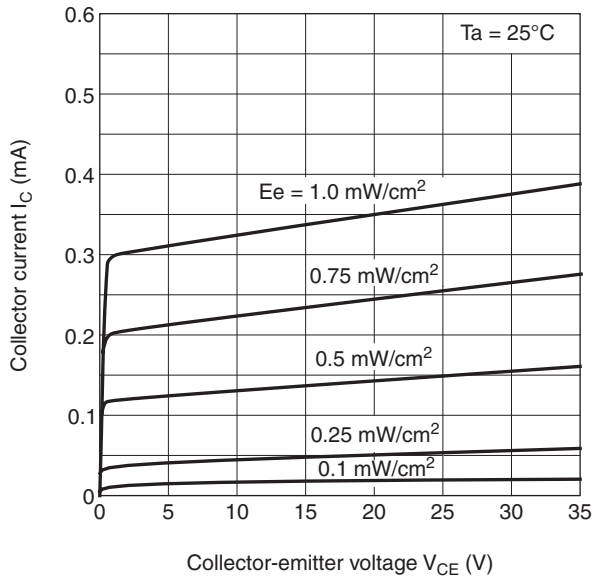


Fig. 8 Test Circuit for Response Time

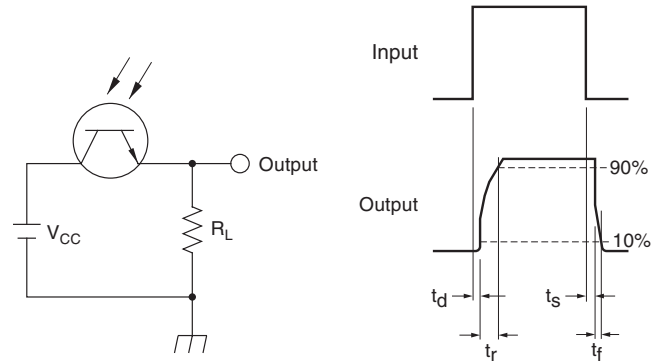


Fig. 9 Sensitivity vs. Axis

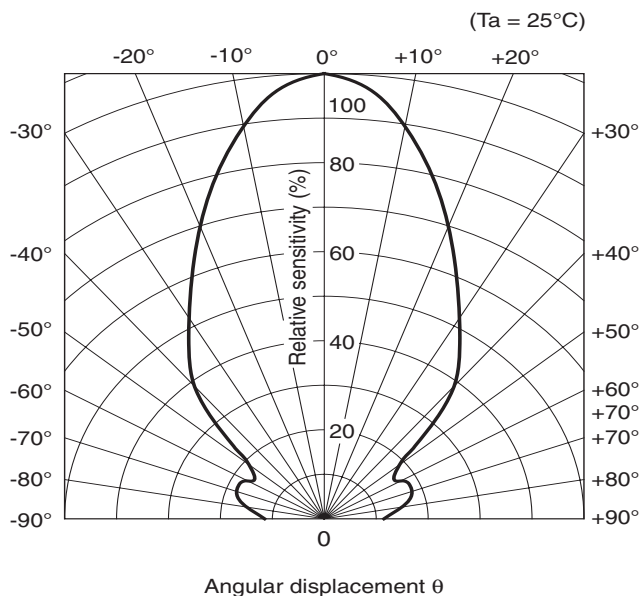


Fig. 11 Relative Output vs Distance

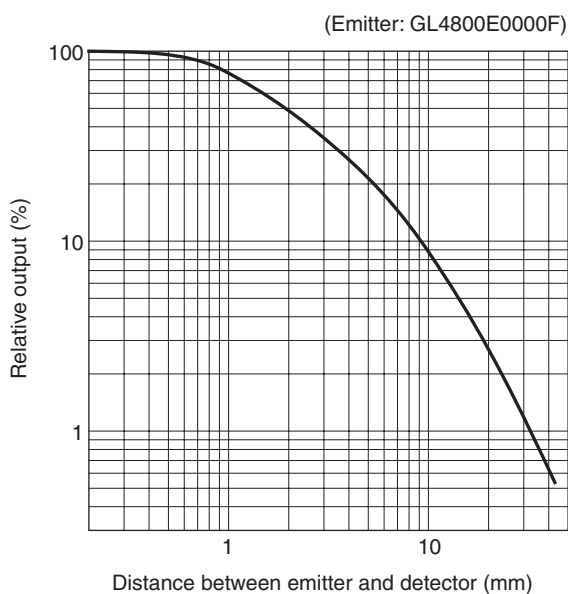
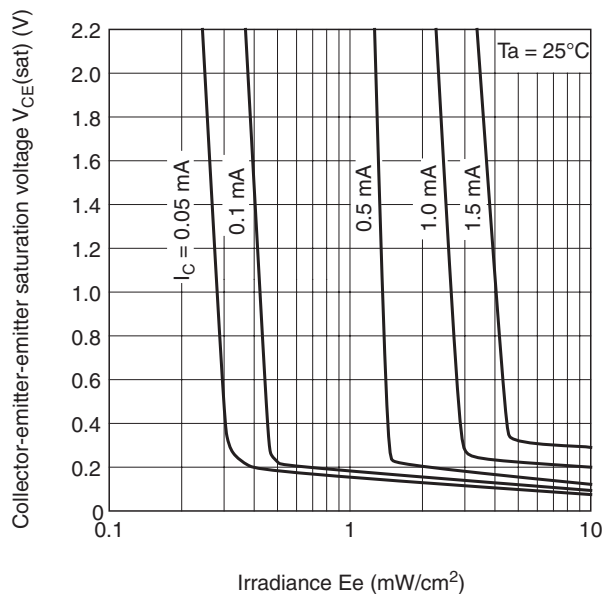


Fig. 10 Collector-to-Emitter Saturation Voltage vs. Irradiance



Graph data is for reference only and is not guaranteed data.

■ Design Notes

1. This product is not designed to resist electromagnetic and ionized-particle radiation.

■ Manufacturing Guidelines

● Soldering Instructions

1. Sharp does not recommend soldering this part using preheat or solder reflow methods. Leads on this part are pre-coated with lead-free solder.
2. If hand soldering, use temperatures $\leq 260^{\circ}\text{C}$ for ≤ 3 seconds.
3. When mounting this device, care should be taken to prevent any boundary exfoliation (pad lifting) between the solder, the pad, and the circuit board.
4. Do not subject the package to excessive mechanical force during soldering as it may cause deformation or defects in plated connections. Internal connections may be severed due to mechanical force placed on the package due to the PCB flexing during the soldering process.

● Cleaning Instructions

1. Confirm this device's resistance to process chemicals before use, as certain process chemicals may affect the optical characteristics.
2. Solvent cleaning: Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.
3. Ultrasonic cleaning: The effect upon devices varies due to cleaning bath size, ultrasonic power output, cleaning time, PCB size and device mounting circumstances. Sharp recommends testing using actual production conditions to confirm the harmlessness of the ultrasonic cleaning methods.
4. Recommended solvent materials: Ethyl alcohol, Methyl alcohol, and Isopropyl alcohol.

■ Presence of ODCs (RoHS Compliance)

This product shall not contain the following materials, and they are not used in the production process for this product:

- Regulated substances: CFCs, Halon, Carbon tetrachloride, 1,1,1-Trichloroethane (Methylchloroform). Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

- Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).
- Content information about the six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (Chinese: 电子信息产品污染控制管理办法)

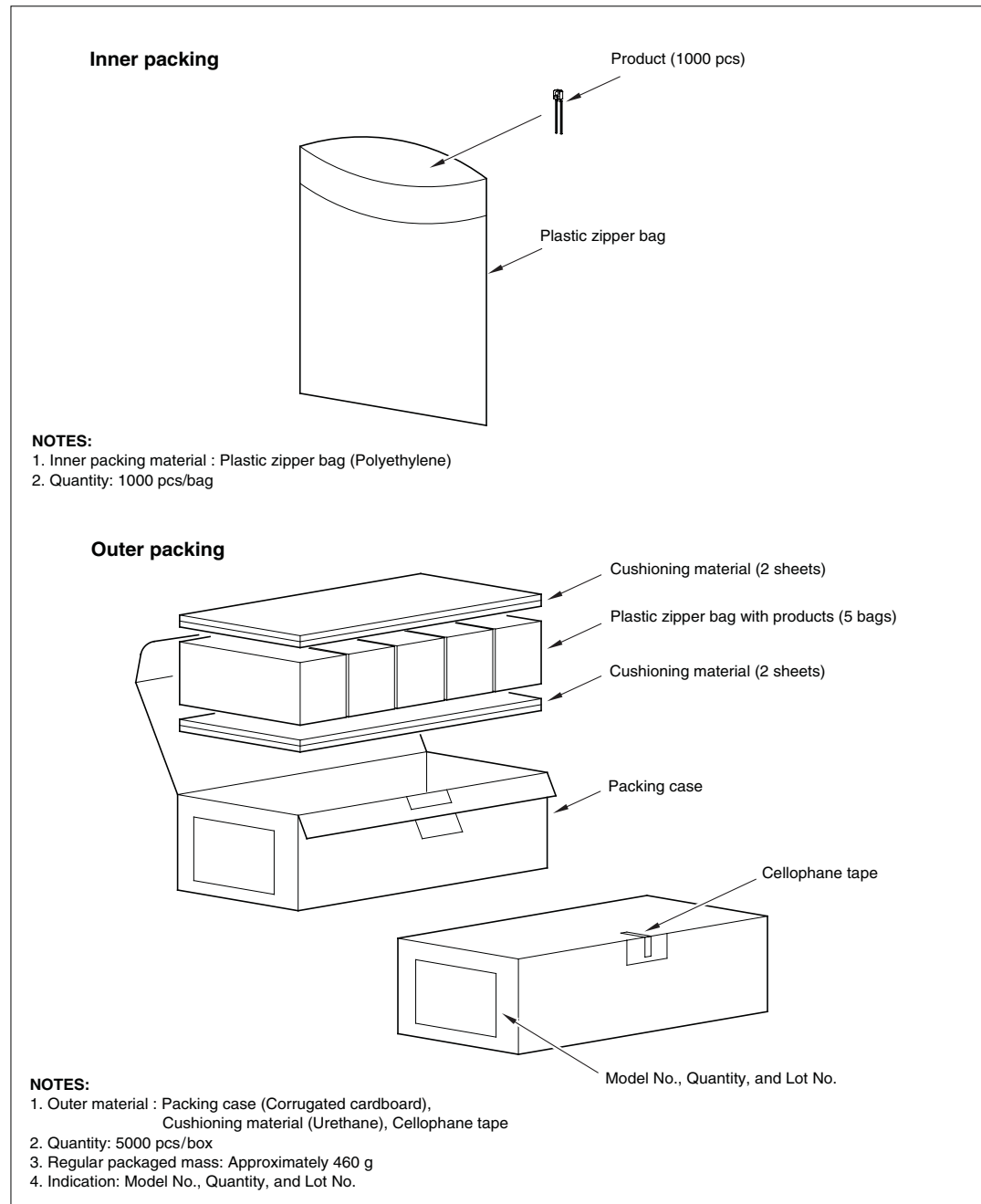
Category	Toxic and Hazardous Substances					
	Lead (Pb)	mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr^{6+})	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)
Photo Transistor	✓	✓	✓	✓	✓	✓

NOTE: ✓ indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.

■ Packing Specifications

1. Parts are packed in a plastic zipper bag, with 1000 pieces per bag.
2. Bags are secured in a box as shown in Figure 12.
3. Product mass: 0.07 g (approximately)

Fig. 12 Packing Composition



■ Important Notices

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(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment (terminal)
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment (trunk lines)
- Nuclear power control equipment
- Medical and other life support equipment (e.g. scuba)

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